

# 74LVC1G53

2-channel analog multiplexer/demultiplexer

Rev. 02 — 10 April 2006

Product data sheet

## 1. General description

The 74LVC1G53 is a high-performance, low-power, low-voltage, Si-gate CMOS device that provides superior performance to most advanced CMOS compatible TTL families.

The 74LVC1G53 provides one analog multiplexer/demultiplexer with a digital select input (S), two independent inputs/outputs (B0 and B1), a common input/output (A) and an active LOW enable input ( $\bar{E}$ ). When pin  $\bar{E}$  is HIGH, the switch is turned off.

The 74LVC1G53 can handle both analog and digital signals.

## 2. Features

- Wide supply voltage range from 1.65 V to 5.5 V
- Very low ON resistance:
  - ◆ 7.5  $\Omega$  (typical) at  $V_{CC} = 2.7$  V
  - ◆ 6.5  $\Omega$  (typical) at  $V_{CC} = 3.3$  V
  - ◆ 6  $\Omega$  (typical) at  $V_{CC} = 5$  V
- High noise immunity
- ESD protection:
  - ◆ HBM JESD22-A114-C exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V
  - ◆ CDM JESD22-C101-C exceeds 1000 V
- CMOS low-power consumption
- Latch-up performance meets requirements of JESD 78 Class I
- Direct interface with TTL levels
- Control inputs accept voltages up to 5 V
- Multiple package options
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

**PHILIPS**

### 3. Quick reference data

**Table 1. Quick reference data**

*GND = 0 V;  $t_f = t_f \leq 2.5 \text{ ns}$ ; minimum and maximum values at  $T_{amb} = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ ;  
typical values at  $T_{amb} = 25^\circ\text{C}$ .*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{on}$	turn-on time S to A or Bn	$C_L = 50 \text{ pF}; R_L = 500 \Omega$				
		$V_{CC} = 3.3 \text{ V}$	1.8	3.4	5.0	ns
		$V_{CC} = 5.0 \text{ V}$	1.3	2.6	3.8	ns
	E to A or Bn	$C_L = 50 \text{ pF}; R_L = 500 \Omega$				
		$V_{CC} = 3.3 \text{ V}$	1.2	2.2	3.8	ns
		$V_{CC} = 5.0 \text{ V}$	1.0	1.7	2.6	ns
$t_{off}$	turn-off time S to A or Bn	$C_L = 50 \text{ pF}; R_L = 500 \Omega$				
		$V_{CC} = 3.3 \text{ V}$	1.1	4.0	5.4	ns
		$V_{CC} = 5.0 \text{ V}$	1.0	2.9	3.8	ns
	E to A or Bn	$C_L = 50 \text{ pF}; R_L = 500 \Omega$				
		$V_{CC} = 3.3 \text{ V}$	2.0	3.7	5.0	ns
		$V_{CC} = 5.0 \text{ V}$	1.3	2.9	3.8	ns
$C_i$	input capacitance		-	2.5	-	pF
$C_{S(OFF)}$	OFF-state capacitance		-	6.0	-	pF
$C_{S(ON)}$	ON-state capacitance		-	18	-	pF

### 4. Ordering information

**Table 2. Ordering information**

Type number	Package			
	Temperature range	Name	Description	Version
74LVC1G53DP	-40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
74LVC1G53DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74LVC1G53GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1

### 5. Marking

**Table 3. Marking**

Type number	Marking code
74LVC1G53DC	V53
74LVC1G53DP	V53
74LVC1G53GT	V53

## 6. Functional diagram

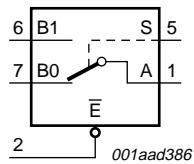


Fig 1. Logic symbol

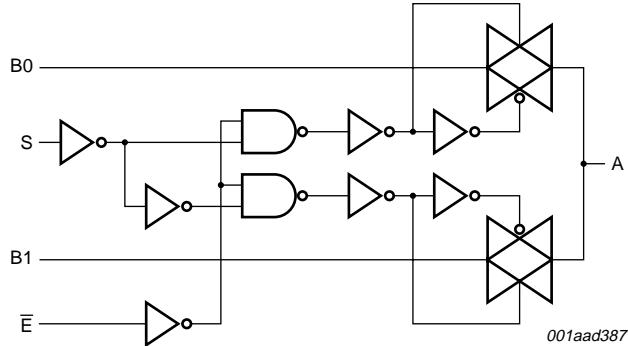


Fig 2. Logic diagram

## 7. Pinning information

### 7.1 Pinning

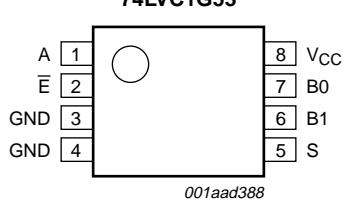


Fig 3. Pin configuration VSSOP8 and TSSOP8

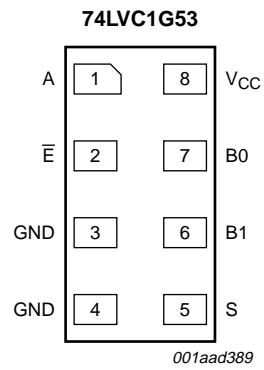


Fig 4. Pin configuration XSON8

## 7.2 Pin description

**Table 4.** Pin description

Symbol	Pin	Description
A	1	common A output or input
$\bar{E}$	2	enable input (active LOW)
GND	3	ground (0 V)
GND	4	ground (0 V)
S	5	select input
B1	6	independent B1 input or output
B0	7	independent B0 input or output
$V_{CC}$	8	supply voltage

## 8. Functional description

### 8.1 Function table

**Table 5.** Function table<sup>[1]</sup>

Input		Channel on
S	$\bar{E}$	
L	L	B0 to A or A to B0
H	L	B1 to A or A to B1
X	H	Z (switch off)

[1] H = HIGH voltage level;  
 L = LOW voltage level;  
 X = don't care;  
 Z = high-impedance OFF-state.

## 9. Limiting values

**Table 6.** Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).  
 Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+6.5	V
$V_I$	input voltage		<sup>[1]</sup> -0.5	+6.5	V
$I_{IK}$	input clamping current	$V_I < -0.5$ V or $V_I > V_{CC} + 0.5$	-	-50	mA
$I_{SK}$	switch clamping current	$V_I < -0.5$ V or $V_I > V_{CC} + 0.5$	-	$\pm 50$	mA
$V_{SW}$	switch voltage	enable and disable mode	-0.5	$V_{CC} + 0.5$	V
$I_{SW}$	switch current	$V_{SW} = -0.5$ V to $(V_{CC} + 0.5)$ V	-	$\pm 50$	mA
$I_{CC}$	quiescent supply current		-	100	mA

**Table 6. Limiting values ...continued**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
I <sub>GND</sub>	ground current		-	-100	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C	[2]	-	300 mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For the TSSOP8 and VSSOP8 packages: above 110 °C the value of P<sub>tot</sub> derates linearly with 8 mW/K.  
For XSON8 package: above 45 °C the value of P<sub>tot</sub> derates linearly with 2.4 mW/K.

## 10. Recommended operating conditions

**Table 7. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V <sub>CC</sub>	supply voltage		1.65	-	5.5	V
V <sub>I</sub>	input voltage		0	-	5.5	V
V <sub>sw</sub>	switch voltage	enable and disable mode	[1] 0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.65 V to 2.7 V	[2] 0	-	20	ns/V
		V <sub>CC</sub> = 2.7 V to 5.5 V	[2] 0	-	10	ns/V

[1] To avoid drawing V<sub>CC</sub> current out of terminal A when switch current flows in terminal Bn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal A, no V<sub>CC</sub> current will flow out of terminal Bn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

## 11. Static characteristics

**Table 8. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

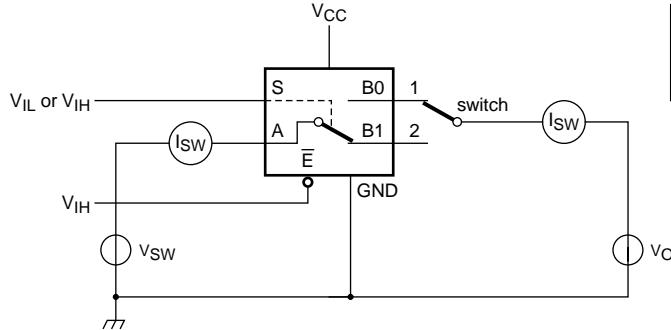
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +85 °C [1]</b>						
V <sub>IH</sub>	HIGH-state input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	0.65V <sub>CC</sub>	-	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	V
		V <sub>CC</sub> = 3 V to 3.6 V	2.0	-	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7V <sub>CC</sub>	-	-	V
V <sub>IL</sub>	LOW-state input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	0.35V <sub>CC</sub>	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	V
		V <sub>CC</sub> = 3 V to 3.6 V	-	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3V <sub>CC</sub>	V
I <sub>LI</sub>	input leakage current	on pin S and pin E; V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 5.5 V	-	±0.1	±2	μA

**Table 8. Static characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

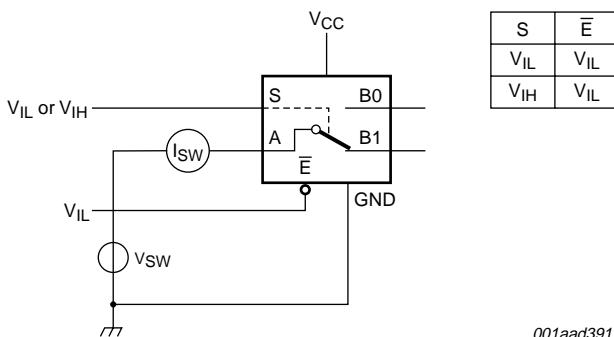
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$I_{S(OFF)}$	OFF-state leakage current	per channel; $V_{SW} = \text{GND}$ and $V_O = V_{CC}$ or $V_{SW} = V_{CC}$ and $V_O = \text{GND}$ ; $V_{CC} = 5.5 \text{ V}$ ; see <a href="#">Figure 5</a>	-	$\pm 0.1$	$\pm 5$	$\mu\text{A}$
$I_{S(ON)}$	ON-state leakage current	per channel; $V_{SW} = \text{GND}$ or $V_{CC}$ ; $V_{CC} = 5.5 \text{ V}$ ; see <a href="#">Figure 6</a>	-	$\pm 0.1$	$\pm 5$	$\mu\text{A}$
$I_{CC}$	quiescent supply current	$V_I = V_{CC}$ or $\text{GND}$ ; $V_{SW} = \text{GND}$ or $V_{CC}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 5.5 \text{ V}$	-	0.1	10	$\mu\text{A}$
$\Delta I_{CC}$	additional quiescent supply current	per input pin; $V_I = V_{CC} - 0.6 \text{ V}$ ; $V_{SW} = \text{GND}$ or $V_{CC}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 5.5 \text{ V}$	-	5	500	$\mu\text{A}$
$C_i$	input capacitance		-	2.5	-	$\text{pF}$
$C_{S(OFF)}$	OFF-state capacitance		-	6.0	-	$\text{pF}$
$C_{S(ON)}$	ON-state capacitance		-	18	-	$\text{pF}$
<b><math>T_{amb} = -40 \text{ }^{\circ}\text{C}</math> to <math>+125 \text{ }^{\circ}\text{C}</math></b>						
$V_{IH}$	HIGH-state input voltage	$V_{CC} = 1.65 \text{ V}$ to $1.95 \text{ V}$	$0.65V_{CC}$	-	-	$\text{V}$
		$V_{CC} = 2.3 \text{ V}$ to $2.7 \text{ V}$	1.7	-	-	$\text{V}$
		$V_{CC} = 3 \text{ V}$ to $3.6 \text{ V}$	2.0	-	-	$\text{V}$
		$V_{CC} = 4.5 \text{ V}$ to $5.5 \text{ V}$	$0.7V_{CC}$	-	-	$\text{V}$
$V_{IL}$	LOW-state input voltage	$V_{CC} = 1.65 \text{ V}$ to $1.95 \text{ V}$	-	-	$0.35V_{CC}$	$\text{V}$
		$V_{CC} = 2.3 \text{ V}$ to $2.7 \text{ V}$	-	-	0.7	$\text{V}$
		$V_{CC} = 3 \text{ V}$ to $3.6 \text{ V}$	-	-	0.8	$\text{V}$
		$V_{CC} = 4.5 \text{ V}$ to $5.5 \text{ V}$	-	-	$0.3V_{CC}$	$\text{V}$
$I_{LI}$	input leakage current	on pin S and pin $\bar{E}$ ; $V_I = 5.5 \text{ V}$ or $\text{GND}$ ; $V_{CC} = 5.5 \text{ V}$	-	-	$\pm 10$	$\mu\text{A}$
$I_{S(OFF)}$	OFF-state leakage current	per channel; $V_{SW} = \text{GND}$ and $V_O = V_{CC}$ or $V_{SW} = V_{CC}$ and $V_O = \text{GND}$ ; $V_{CC} = 5.5 \text{ V}$ ; see <a href="#">Figure 5</a>	-	-	$\pm 20$	$\mu\text{A}$
$I_{S(ON)}$	ON-state leakage current	per channel; $V_{SW} = \text{GND}$ or $V_{CC}$ ; $V_{CC} = 5.5 \text{ V}$ ; see <a href="#">Figure 6</a>	-	-	$\pm 20$	$\mu\text{A}$
$I_{CC}$	quiescent supply current	$V_I = V_{CC}$ or $\text{GND}$ ; $V_{SW} = \text{GND}$ or $V_{CC}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 5.5 \text{ V}$	-	-	40	$\mu\text{A}$
$\Delta I_{CC}$	additional quiescent supply current	per input pin; $V_I = V_{CC} - 0.6 \text{ V}$ ; $V_{SW} = \text{GND}$ or $V_{CC}$ ; $I_O = 0 \text{ A}$ ; $V_{CC} = 5.5 \text{ V}$	-	-	5000	$\mu\text{A}$

[1] Typical values are measured at  $T_{amb} = 25 \text{ }^{\circ}\text{C}$ .



$V_{SW} = V_{CC}$  or  $GND$ ;  $v_O = GND$  or  $V_{CC}$ .

Fig 5. Test circuit for measuring switch OFF-state current



$V_{SW} = V_{CC}$  or  $GND$ .

Fig 6. Test circuit for measuring switch ON-state current

Table 9. Resistance  $R_{on}$

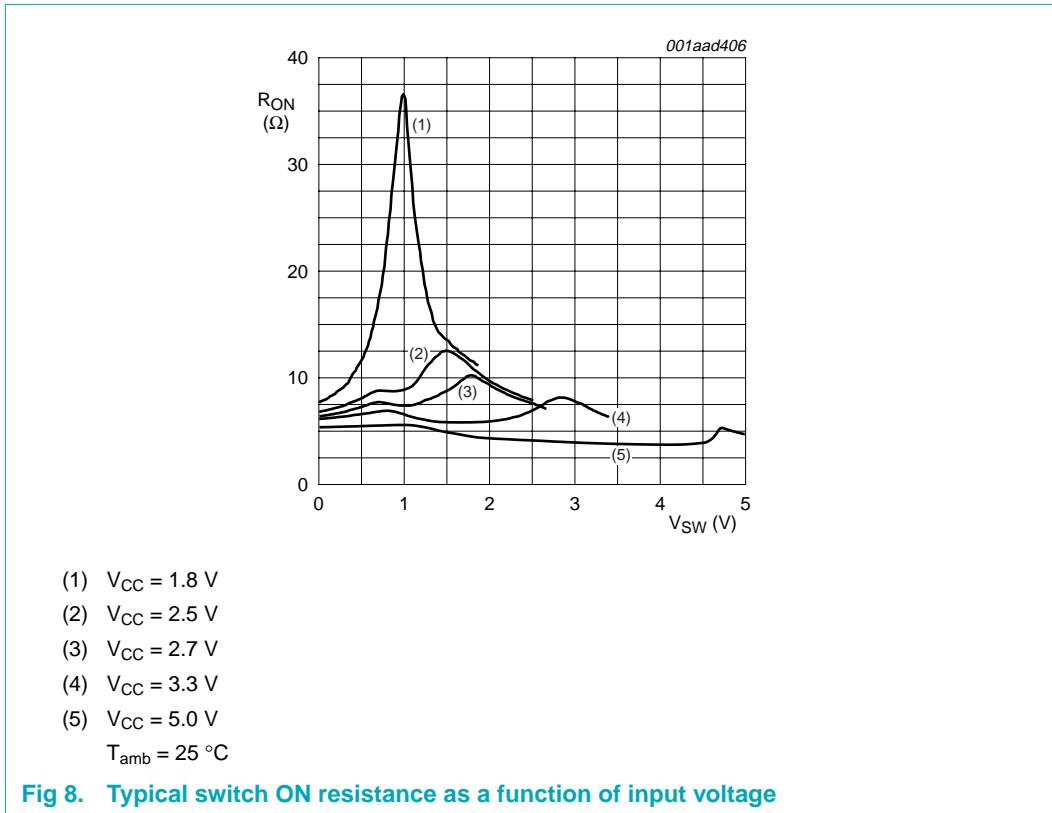
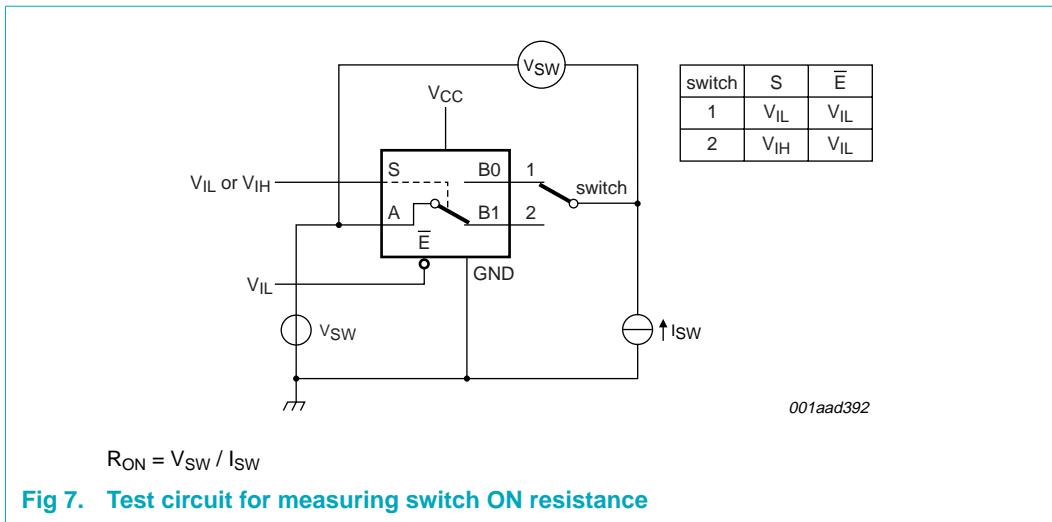
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); see test circuit [Figure 7](#).

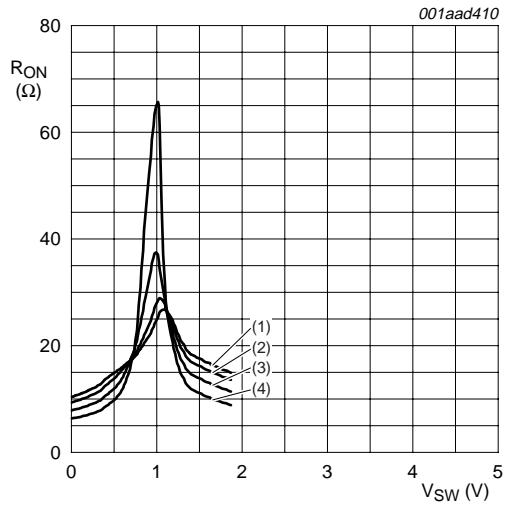
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ <sup>[1]</sup>						
$R_{ON(rail)}$	ON resistance (rail)	$V_{SW} = GND$				
		$I_{SW} = 4 \text{ mA}; V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	8.7	18	$\Omega$
		$I_{SW} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	7.2	16	$\Omega$
		$I_{SW} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	7.0	14	$\Omega$
		$I_{SW} = 24 \text{ mA}; V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	-	6.5	12	$\Omega$
		$I_{SW} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	5.9	10	$\Omega$
$V_{SW} = V_{CC}$						
		$I_{SW} = 4 \text{ mA}; V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	12	30	$\Omega$
		$I_{SW} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	8.3	20	$\Omega$
		$I_{SW} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	7.8	18	$\Omega$
		$I_{SW} = 24 \text{ mA}; V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	-	6.7	15	$\Omega$
		$I_{SW} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	5.2	10	$\Omega$

**Table 9. Resistance  $R_{on}$  ...continued**At recommended operating conditions; voltages are referenced to GND (ground = 0 V); see test circuit [Figure 7](#).

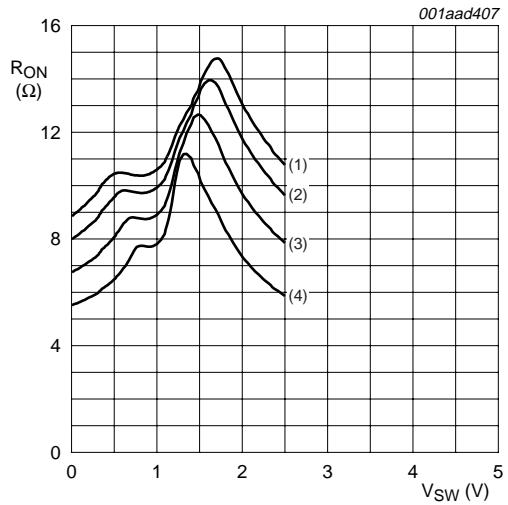
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{ON(peak)}$	ON resistance (peak)	$V_{SW} = \text{GND to } V_{CC}$				
		$I_{SW} = 4 \text{ mA}; V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	57	130	$\Omega$
		$I_{SW} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	15	30	$\Omega$
		$I_{SW} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	13	25	$\Omega$
		$I_{SW} = 24 \text{ mA}; V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	-	9.0	20	$\Omega$
$R_{ON(flat)}$	ON resistance (flatness)	$V_{SW} = \text{GND to } V_{CC}$ ; see <a href="#">Figure 9</a>				
		$I_{SW} = 4 \text{ mA}; V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	100	-	$\Omega$
		$I_{SW} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	17	-	$\Omega$
		$I_{SW} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	10	-	$\Omega$
		$I_{SW} = 24 \text{ mA}; V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	-	5	-	$\Omega$
$T_{amb} = -40 \text{ }^{\circ}\text{C to } +125 \text{ }^{\circ}\text{C}$	$R_{ON(rail)}$	$V_{SW} = \text{GND}$				
		$I_{SW} = 4 \text{ mA}; V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	-	27	$\Omega$
		$I_{SW} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	-	24	$\Omega$
		$I_{SW} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	21	$\Omega$
		$I_{SW} = 24 \text{ mA}; V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	-	-	18	$\Omega$
	$R_{ON(peak)}$	$I_{SW} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	15	$\Omega$
		$V_{SW} = V_{CC}$				
		$I_{SW} = 4 \text{ mA}; V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	-	45	$\Omega$
		$I_{SW} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	-	30	$\Omega$
		$I_{SW} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	-	-	27	$\Omega$
[1]	Typical values are measured at $T_{amb} = 25 \text{ }^{\circ}\text{C}$ and nominal $V_{CC}$ .	$I_{SW} = 24 \text{ mA}; V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	-	-	23	$\Omega$
		$I_{SW} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	15	$\Omega$

[1] Typical values are measured at  $T_{amb} = 25 \text{ }^{\circ}\text{C}$  and nominal  $V_{CC}$ .

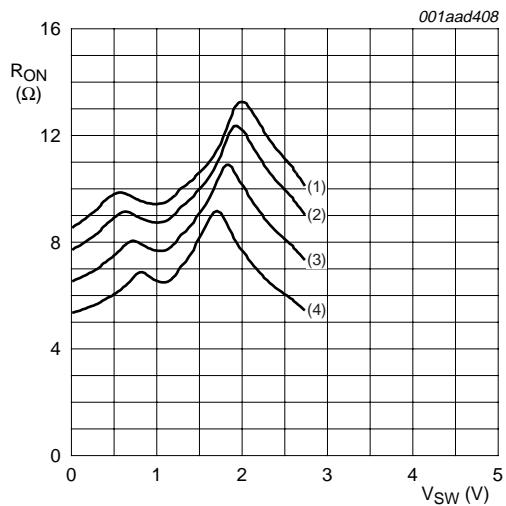




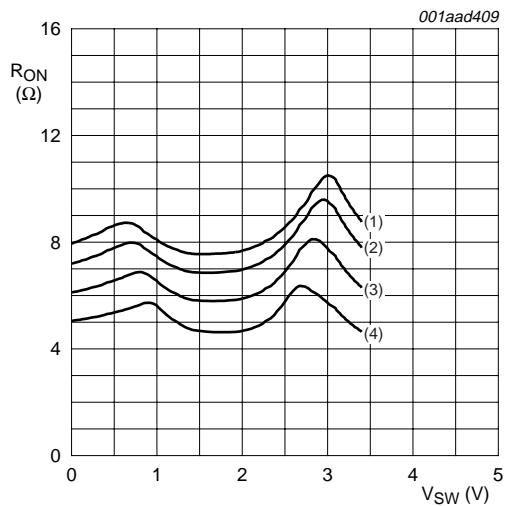
- (1)  $T_{amb} = 125$  °C
- (2)  $T_{amb} = 85$  °C
- (3)  $T_{amb} = 25$  °C
- (4)  $T_{amb} = -40$  °C
- a.  $V_{CC} = 1.8$  V



- (1)  $T_{amb} = 125$  °C
- (2)  $T_{amb} = 85$  °C
- (3)  $T_{amb} = 25$  °C
- (4)  $T_{amb} = -40$  °C
- b.  $V_{CC} = 2.5$  V



- (1)  $T_{amb} = 125$  °C
- (2)  $T_{amb} = 85$  °C
- (3)  $T_{amb} = 25$  °C
- (4)  $T_{amb} = -40$  °C
- c.  $V_{CC} = 2.7$  V



- (1)  $T_{amb} = 125$  °C
- (2)  $T_{amb} = 85$  °C
- (3)  $T_{amb} = 25$  °C
- (4)  $T_{amb} = -40$  °C
- d.  $V_{CC} = 3.3$  V

**Fig 9. Switch ON resistance as a function of switch voltage**

## 12. Dynamic characteristics

**Table 10. Dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); test circuit [Figure 12](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +85 °C[1]</b>						
t <sub>PHL</sub>	HIGH-to-LOW propagation delay	see <a href="#">Figure 10</a>				
	A to Bn or Bn to A	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	1.2	ns
		V <sub>CC</sub> = 2.7 V	-	-	1.0	ns
		V <sub>CC</sub> = 3 V to 3.6 V	-	-	0.8	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.6	ns
t <sub>PLH</sub>	LOW-to-HIGH propagation delay	see <a href="#">Figure 10</a>				
	A to Bn or Bn to A	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	1.2	ns
		V <sub>CC</sub> = 2.7 V	-	-	1.0	ns
		V <sub>CC</sub> = 3 V to 3.6 V	-	-	0.8	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.6	ns
t <sub>on</sub>	turn-on time	see <a href="#">Figure 11</a>				
	S to A or Bn	V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	6.7	10.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.9	4.1	6.4	ns
		V <sub>CC</sub> = 2.7 V	1.9	4.0	5.5	ns
		V <sub>CC</sub> = 3 V to 3.6 V	1.8	3.4	5.0	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.3	2.6	3.8	ns
	Ē to A or Bn	V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	4.0	7.3	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	2.5	4.4	ns
		V <sub>CC</sub> = 2.7 V	1.1	2.6	3.9	ns
		V <sub>CC</sub> = 3 V to 3.6 V	1.2	2.2	3.8	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.0	1.7	2.6	ns
t <sub>off</sub>	turn-off time	see <a href="#">Figure 11</a>				
	S to A or Bn	V <sub>CC</sub> = 1.65 V to 1.95 V	2.1	6.8	10.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	3.7	6.1	ns
		V <sub>CC</sub> = 2.7 V	1.4	4.9	6.2	ns
		V <sub>CC</sub> = 3 V to 3.6 V	1.1	4.0	5.4	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.0	2.9	3.8	ns
	Ē to A or Bn	V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	5.6	8.6	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.2	3.2	4.8	ns
		V <sub>CC</sub> = 2.7 V	1.4	4.0	5.2	ns
		V <sub>CC</sub> = 3 V to 3.6 V	2.0	3.7	5.0	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.3	2.9	3.8	ns

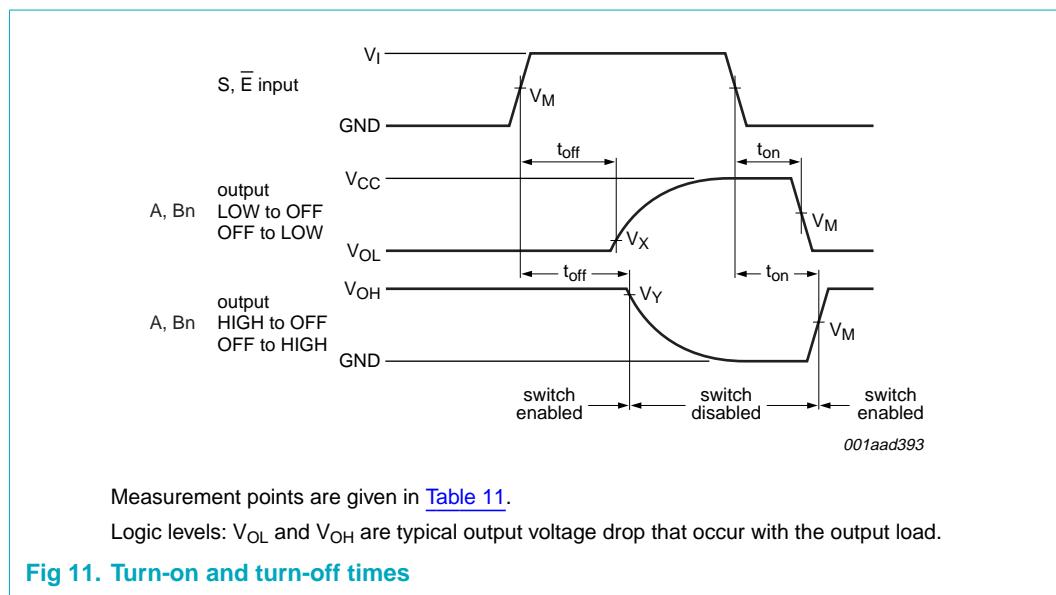
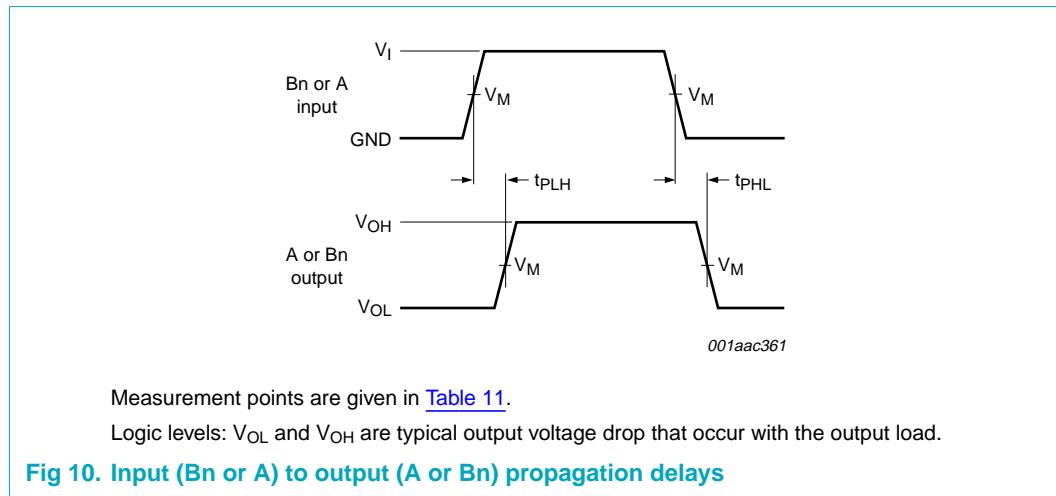
**Table 10. Dynamic characteristics ...continued**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); test circuit [Figure 12](#).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>T<sub>amb</sub> = -40 °C to +125 °C</b>						
t <sub>PHL</sub>	HIGH-to-LOW propagation delay	see <a href="#">Figure 10</a>				
	A to Bn or Bn to A	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	2.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	1.5	ns
		V <sub>CC</sub> = 2.7 V	-	-	1.25	ns
		V <sub>CC</sub> = 3 V to 3.6 V	-	-	1.0	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	ns
t <sub>PLH</sub>	LOW-to-HIGH propagation delay	see <a href="#">Figure 10</a>				
	A to Bn or Bn to A	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	2.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	1.5	ns
		V <sub>CC</sub> = 2.7 V	-	-	1.25	ns
		V <sub>CC</sub> = 3 V to 3.6 V	-	-	1.0	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	ns
t <sub>on</sub>	turn-on time	see <a href="#">Figure 11</a>				
	S to A or Bn	V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	-	12.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.9	-	8.0	ns
		V <sub>CC</sub> = 2.7 V	1.8	-	7.0	ns
		V <sub>CC</sub> = 3 V to 3.6 V	1.8	-	6.3	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.3	-	4.8	ns
	Ē to A or Bn	V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	-	9.2	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	-	5.5	ns
		V <sub>CC</sub> = 2.7 V	1.1	-	4.9	ns
		V <sub>CC</sub> = 3 V to 3.6 V	1.2	-	4.8	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.0	-	3.3	ns
t <sub>off</sub>	turn-off time	see <a href="#">Figure 11</a>				
	S to A or Bn	V <sub>CC</sub> = 1.65 V to 1.95 V	2.1	-	12.5	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.4	-	7.7	ns
		V <sub>CC</sub> = 2.7 V	1.4	-	7.8	ns
		V <sub>CC</sub> = 3 V to 3.6 V	1.1	-	6.8	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.0	-	4.8	ns
	Ē to A or Bn	V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	-	11.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.2	-	6.0	ns
		V <sub>CC</sub> = 2.7 V	1.4	-	6.5	ns
		V <sub>CC</sub> = 3 V to 3.6 V	2.0	-	6.3	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	1.3	-	4.8	ns

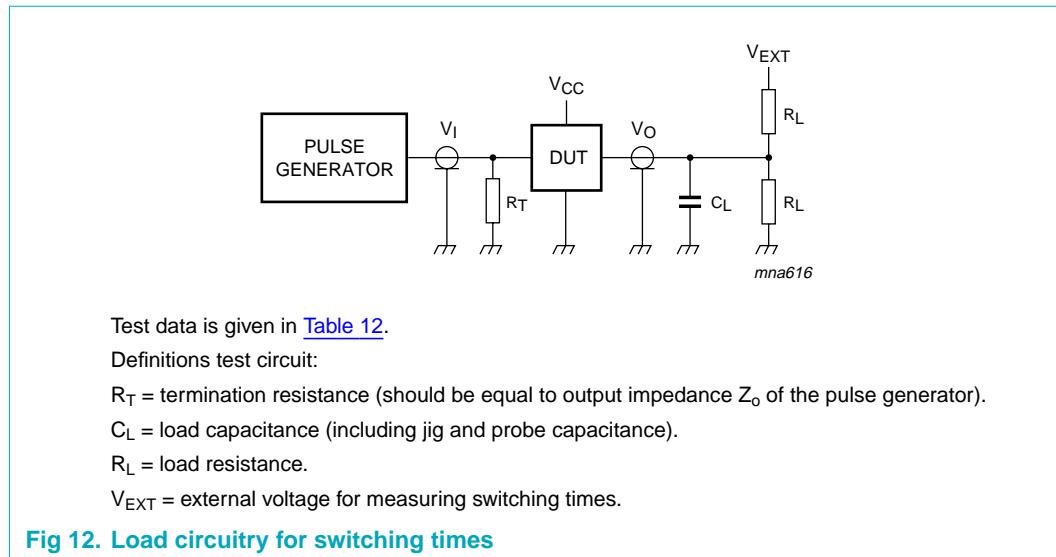
[1] Typical values are measured at T<sub>amb</sub> = 25 °C and nominal V<sub>CC</sub>.

## 13. Waveforms



**Table 11. Measurement points**

Supply voltage	Input	Output		
$V_{CC}$	$V_M$	$V_M$	$V_X$	$V_Y$
1.65 V to 2.7 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.15$ V	$V_{OH} - 0.15$ V
2.7 V to 5.5 V	$0.5V_{CC}$	$0.5V_{CC}$	$V_{OL} + 0.3$ V	$V_{OH} - 0.3$ V

**Table 12. Test data**

Supply voltage $V_{CC}$	Input		Load		$t_{PLH}, t_{PHL}$	$t_{on}, t_{off}$	$V_{EXT}$	
	$V_I$	$t_r, t_f$	$C_L$	$R_L$			HIGH to OFF OFF to HIGH	LOW to OFF OFF to LOW
1.65 V to 1.95 V	$V_{CC}$	$\leq 2.0$ ns	30 pF	1 k $\Omega$	open	GND	2 $\times V_{CC}$	
2.3 V to 2.7 V	$V_{CC}$	$\leq 2.0$ ns	30 pF	500 $\Omega$	open	GND	2 $\times V_{CC}$	
2.7 V	$V_{CC}$	$\leq 2.5$ ns	50 pF	500 $\Omega$	open	GND	2 $\times V_{CC}$	
3 V to 3.6 V	$V_{CC}$	$\leq 2.5$ ns	50 pF	500 $\Omega$	open	GND	2 $\times V_{CC}$	
4.5 V to 5.5 V	$V_{CC}$	$\leq 2.5$ ns	50 pF	500 $\Omega$	open	GND	2 $\times V_{CC}$	

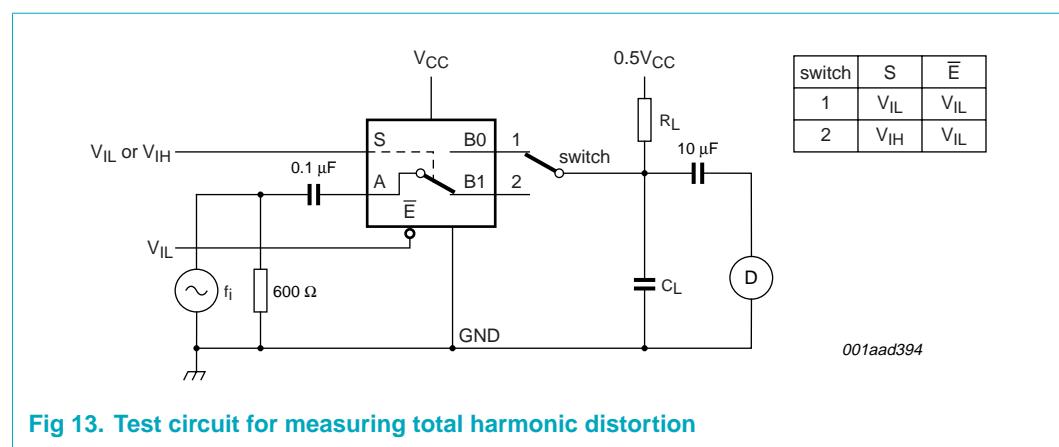
## 14. Additional dynamic characteristics

**Table 13. Additional dynamic characteristics**At recommended operating conditions; typical values measured at  $T_{amb} = 25^\circ C$ .

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
THD	total harmonic distortion	$f_i = 600$ Hz to 20 kHz; $R_L = 600 \Omega$ ; $C_L = 50$ pF; $V_I = 0.5$ V (p-p); see <a href="#">Figure 13</a>				
		$V_{CC} = 1.65$ V	-	0.260	-	%
		$V_{CC} = 2.3$ V	-	0.078	-	%
		$V_{CC} = 3.0$ V	-	0.078	-	%
		$V_{CC} = 4.5$ V	-	0.078	-	%
$f_{(-3dB)}$	$-3$ dB frequency response	$R_L = 50 \Omega$ ; $C_L = 5$ pF; see <a href="#">Figure 14</a>	[1]			
		$V_{CC} = 1.65$ V	-	200	-	MHz
		$V_{CC} = 2.3$ V	-	300	-	MHz
		$V_{CC} = 3.0$ V	-	300	-	MHz
		$V_{CC} = 4.5$ V	-	300	-	MHz

**Table 13. Additional dynamic characteristics ...continued**At recommended operating conditions; typical values measured at  $T_{amb} = 25^{\circ}\text{C}$ .

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$\alpha_{OFF(f)}$	OFF-state feed-through attenuation	$R_L = 50 \Omega$ ; $C_L = 5 \text{ pF}$ ; $f_i = 10 \text{ MHz}$ ; see <a href="#">Figure 15</a>	[2]			
		$V_{CC} = 1.65 \text{ V}$	-	-42	-	dB
		$V_{CC} = 2.3 \text{ V}$	-	-42	-	dB
		$V_{CC} = 3.0 \text{ V}$	-	-40	-	dB
		$V_{CC} = 4.5 \text{ V}$	-	-40	-	dB
$V_{ct(sw-sw)}$	crosstalk between switches	$R_L = 50 \Omega$ ; $C_L = 5 \text{ pF}$ ; $f_i = 10 \text{ MHz}$ ; see <a href="#">Figure 16</a>				
		$V_{CC} = 1.65 \text{ V}$	-	-68	-	dBV
		$V_{CC} = 2.3 \text{ V}$	-	-70	-	dBV
		$V_{CC} = 3.0 \text{ V}$	-	-70	-	dBV
		$V_{CC} = 4.5 \text{ V}$	-	-70	-	dBV
$Q_{inj}$	charge injection	$C_L = 0.1 \text{ nF}$ ; $V_{gen} = 0 \text{ V}$ ; $R_{gen} = 0 \Omega$ ; $f_i = 1 \text{ MHz}$ ; $R_L = 1 \text{ M}\Omega$ ; see <a href="#">Figure 17</a>	[3]			
		$V_{CC} = 1.8 \text{ V}$	-	< 0.003	-	pC
		$V_{CC} = 2.5 \text{ V}$	-	0.004	-	pC
		$V_{CC} = 3.3 \text{ V}$	-	0.0045	-	pC
		$V_{CC} = 4.5 \text{ V}$	-	0.0045	-	pC
		$V_{CC} = 5.5 \text{ V}$	-	0.0045	-	pC

[1] Adjust  $f_i$  voltage to obtain 0 dBm level at output. Increase  $f_i$  frequency until dB meter reads -3 dB.[2] Adjust  $f_i$  voltage to obtain 0 dBm level at input.[3] Definition:  $Q_{inj} = \Delta V_O \times C_L$ . Guaranteed by design.

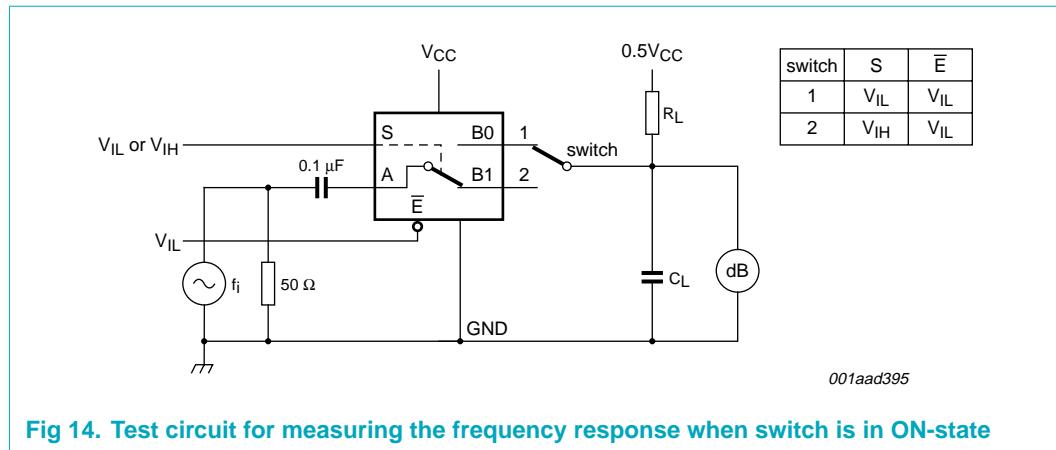


Fig 14. Test circuit for measuring the frequency response when switch is in ON-state

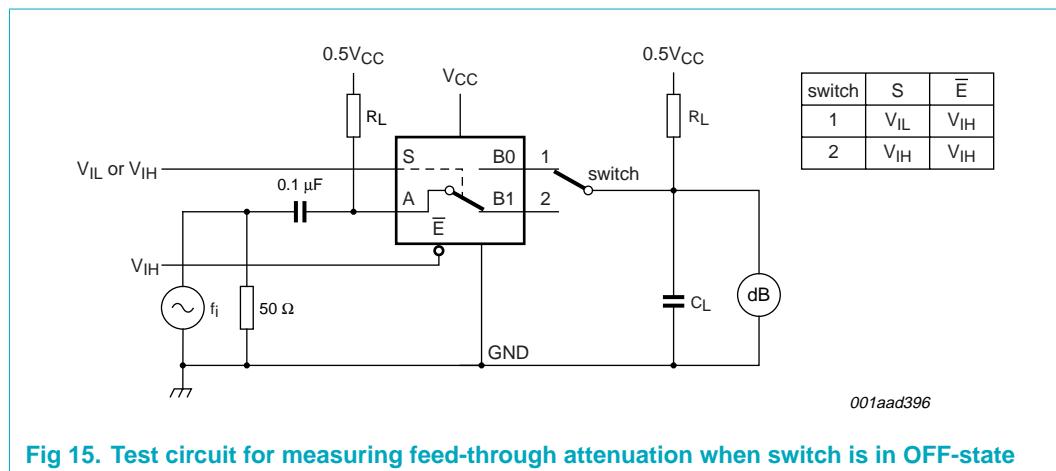


Fig 15. Test circuit for measuring feed-through attenuation when switch is in OFF-state

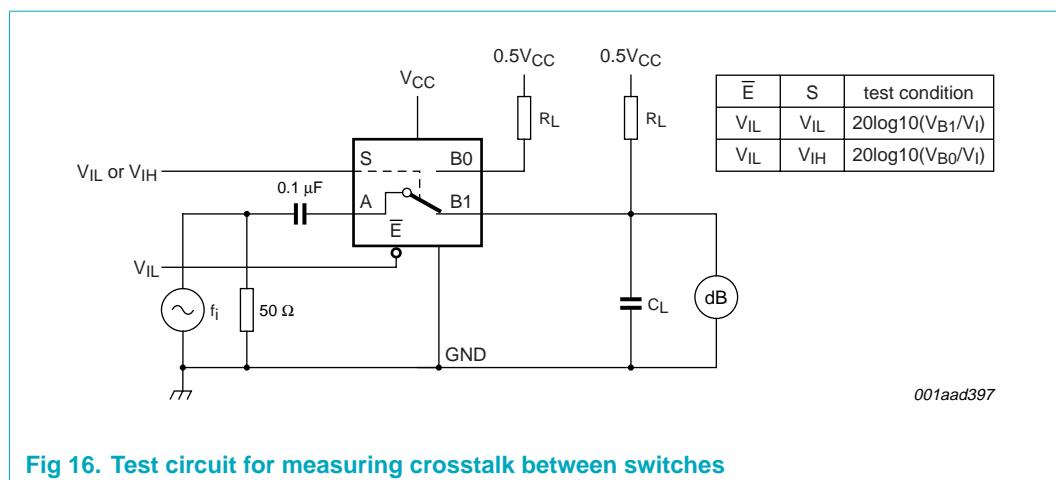
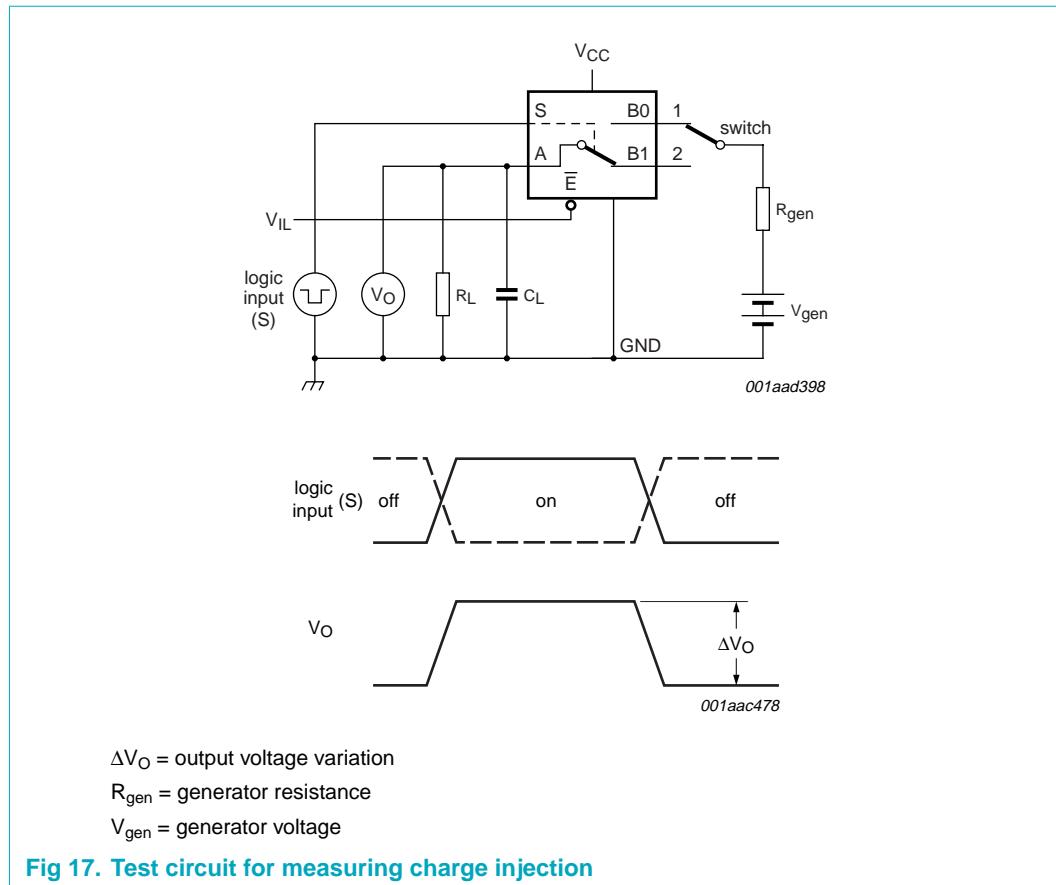


Fig 16. Test circuit for measuring crosstalk between switches



## 15. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

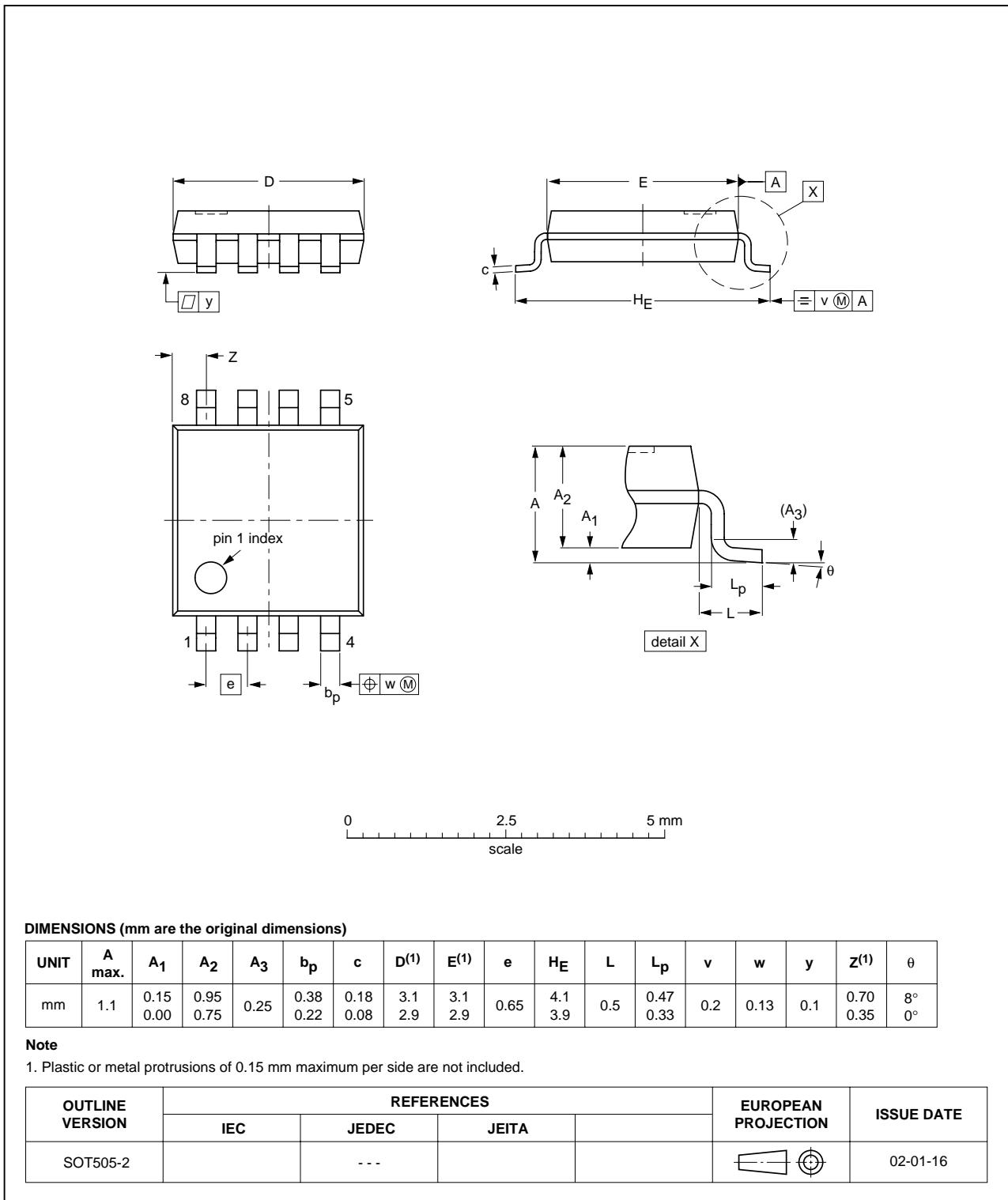


Fig 18. Package outline SOT505-2 (TSSOP8)

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

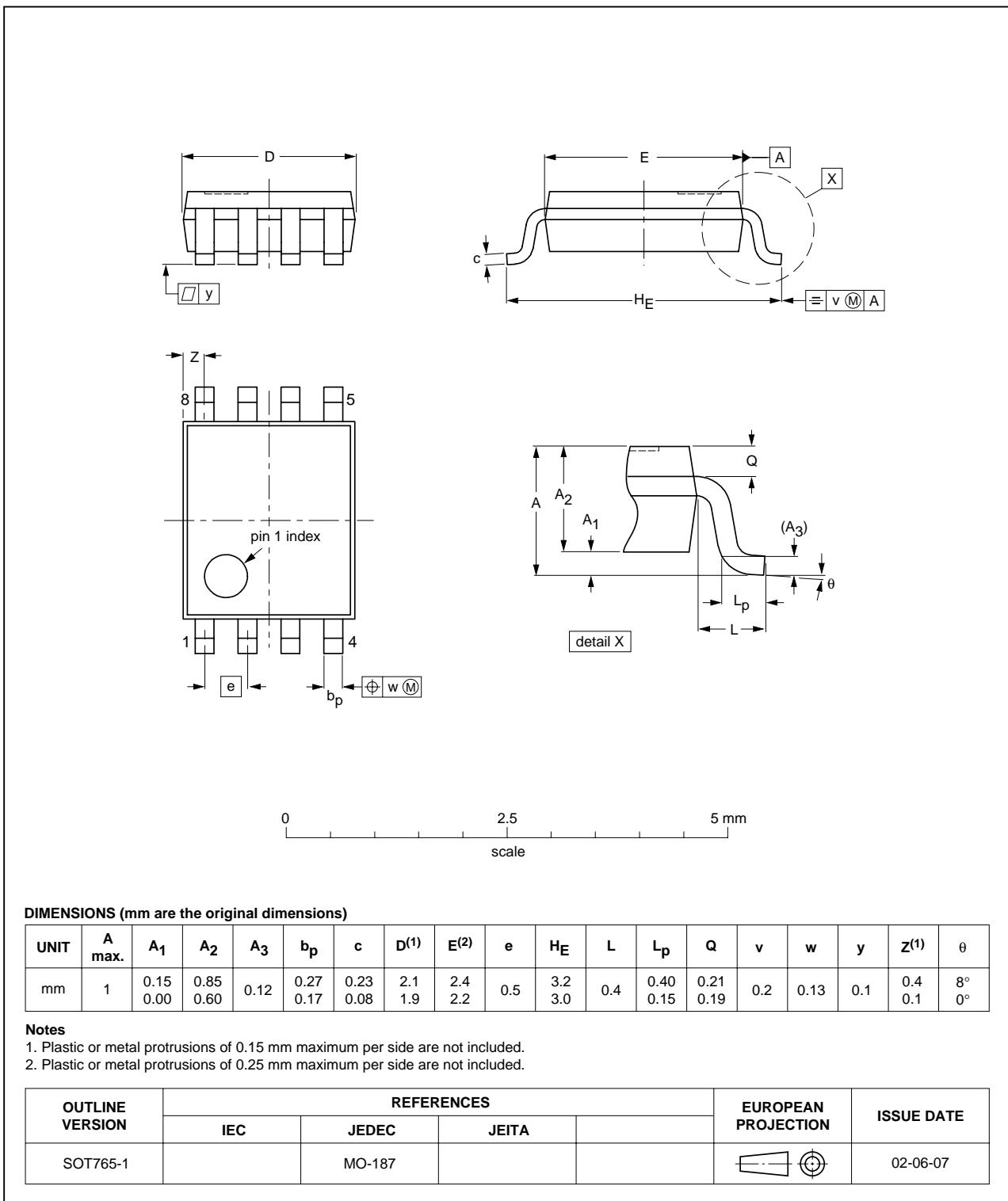


Fig 19. Package outline SOT765-1 (VSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm

SOT833-1

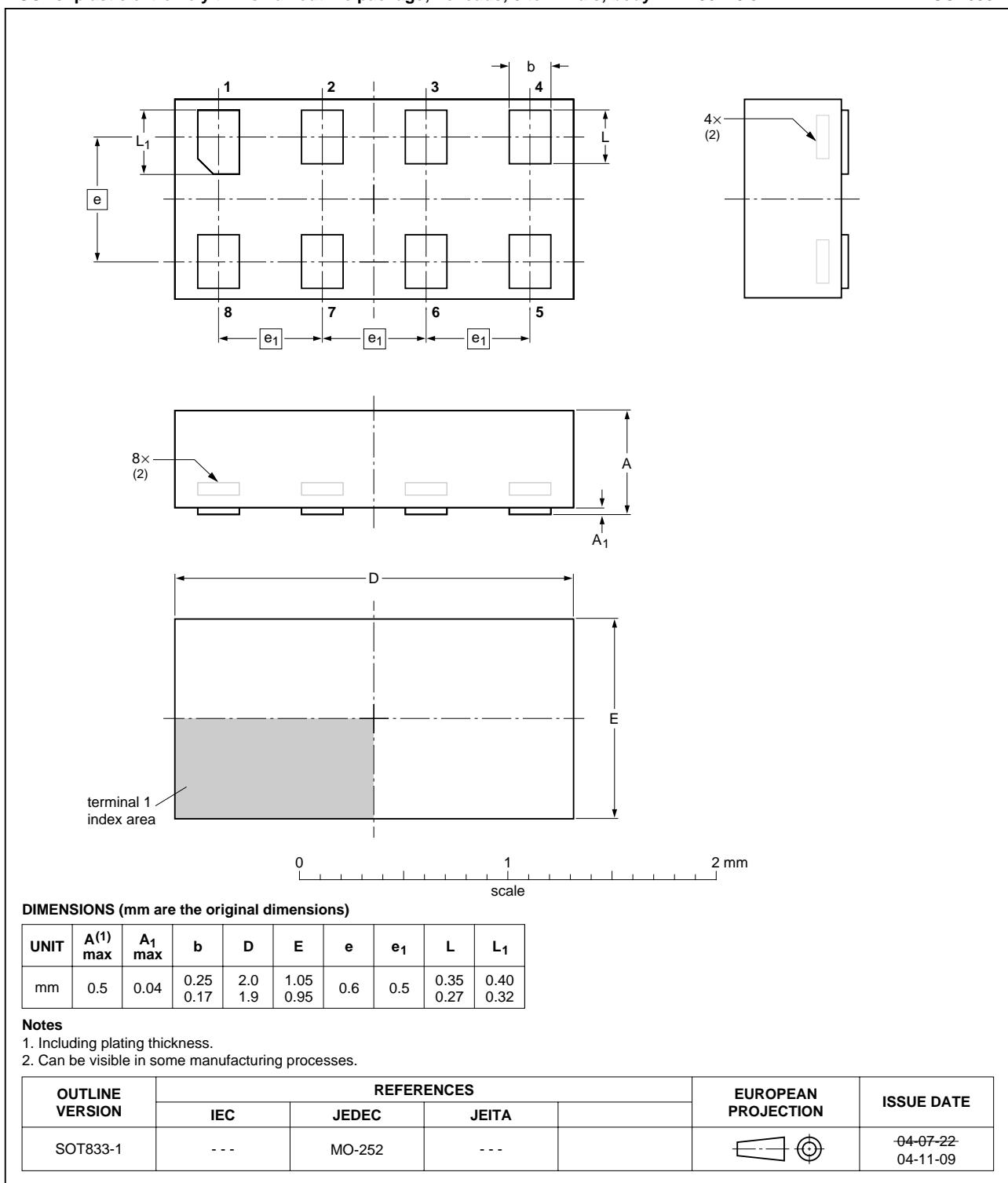


Fig 20. Package outline SOT833-1 (XSON8)

## 16. Abbreviations

**Table 14. Abbreviations**

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
TTL	Transistor-Transistor Logic
HBM	Human Body Model
ESD	ElectroStatic Discharge
MM	Machine Model
CDM	Charged Device Model
DUT	Device Under Test

## 17. Revision history

**Table 15. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G53_2	20060410	Product data sheet	-	74LVC1G53_1
Modifications:		• TSSOP8 (SOT505_2) package added		
74LVC1G53_1	20060110	Product data sheet	-	-

## 18. Legal information

### 18.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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## 20. Contents

1	General description .....	1
2	Features .....	1
3	Quick reference data .....	2
4	Ordering information .....	2
5	Marking .....	2
6	Functional diagram .....	3
7	Pinning information .....	3
7.1	Pinning .....	3
7.2	Pin description .....	4
8	Functional description .....	4
8.1	Function table .....	4
9	Limiting values .....	4
10	Recommended operating conditions .....	5
11	Static characteristics .....	5
12	Dynamic characteristics .....	11
13	Waveforms .....	13
14	Additional dynamic characteristics .....	14
15	Package outline .....	18
16	Abbreviations .....	21
17	Revision history .....	21
18	Legal information .....	22
18.1	Data sheet status .....	22
18.2	Definitions .....	22
18.3	Disclaimers .....	22
18.4	Trademarks .....	22
19	Contact information .....	22
20	Contents .....	23

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